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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	120MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I ² C, IrDA, SD, SPI, UART/USART, USB, USB OTG
Peripherals	DMA, I ² S, LVD, POR, PWM, WDT
Number of I/O	100
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	128K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 58x16b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LBGA
Supplier Device Package	144-MAPBGA (13x13)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mk60fn1m0vmd12

- Communication interfaces
 - Ethernet controller with MII and RMII interface to external PHY and hardware IEEE 1588 capability
 - USB high-/full-/low-speed On-the-Go controller with ULPI interface
 - USB full-/low-speed On-the-Go controller with on-chip transceiver
 - USB Device Charger detect (USBDCD)
 - Two Controller Area Network (CAN) modules
 - Three SPI modules
 - Two I2C modules
 - Six UART modules
 - Secure Digital Host Controller (SDHC)
 - Two I2S modules

1 Ordering parts

1.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to freescale.com and perform a part number search for the following device numbers: PK60 and MK60

2 Part identification

2.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

2.2 Format

Part numbers for this device have the following format:

Q K## A M FFF T PP CC N

2.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

Field	Description	Values
Q	Qualification status	<ul style="list-style-type: none"> M = Fully qualified, general market flow P = Prequalification
K##	Kinetis family	<ul style="list-style-type: none"> K60
A	Key attribute	<ul style="list-style-type: none"> F = Cortex-M4 w/ DSP and FPU
M	Flash memory type	<ul style="list-style-type: none"> N = Program flash only X = Program flash and FlexMemory
FFF	Program flash memory size	<ul style="list-style-type: none"> 512 = 512 KB 1M0 = 1 MB

Table continues on the next page...

4.2 Moisture handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
MSL	Moisture sensitivity level	—	3	—	1

1. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

4.3 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
V _{HBM}	Electrostatic discharge voltage, human body model	-2000	+2000	V	1
V _{CDM}	Electrostatic discharge voltage, charged-device model	-500	+500	V	2
I _{LAT}	Latch-up current at ambient temperature of 105°C	-100	+100	mA	3

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.
3. Determined according to JEDEC Standard JESD78, *IC Latch-Up Test*.

4.4 Voltage and current operating ratings

Symbol	Description	Min.	Max.	Unit
V _{DD}	Digital supply voltage ¹	-0.3	3.8	V
I _{DD}	Digital supply current	—	300	mA
V _{DIO}	Digital input voltage (except $\overline{\text{RESET}}$, EXTAL0/XTAL0, and EXTAL1/XTAL1) ²	-0.3	5.5	V
V _{AIO}	Analog ³ , $\overline{\text{RESET}}$, EXTAL0/XTAL0, and EXTAL1/XTAL1 input voltage	-0.3	V _{DD} + 0.3	V
I _D	Maximum current single pin limit (applies to all digital pins)	-25	25	mA
V _{DDA}	Analog supply voltage	V _{DD} - 0.3	V _{DD} + 0.3	V
V _{USB0_DP}	USB0_DP input voltage	-0.3	3.63	V
V _{USB1_DP}	USB1_DP input voltage	-0.3	3.63	V
V _{USB0_DM}	USB0_DM input voltage	-0.3	3.63	V
V _{USB1_DM}	USB1_DM input voltage	-0.3	3.63	V
V _{REGIN}	USB regulator input	-0.3	6.0	V
V _{BAT}	RTC battery supply voltage	-0.3	3.8	V

1. It applies for all port pins.

5.2.2 LVD and POR operating requirements

Table 2. LVD and POR operating requirements

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V _{POR}	Falling VDD POR detect voltage	0.8	1.1	1.5	V	
V _{LVDH}	Falling low-voltage detect threshold — high range (LVDV=01)	2.48	2.56	2.64	V	
V _{LW1H} V _{LW2H} V _{LW3H} V _{LW4H}	Low-voltage warning thresholds — high range <ul style="list-style-type: none"> • Level 1 falling (LVWV=00) • Level 2 falling (LVWV=01) • Level 3 falling (LVWV=10) • Level 4 falling (LVWV=11) 	2.62 2.72 2.82 2.92	2.70 2.80 2.90 3.00	2.78 2.88 2.98 3.08	V V V V	1
V _{HYSH}	Low-voltage inhibit reset/recover hysteresis — high range	—	±80	—	mV	
V _{LVDL}	Falling low-voltage detect threshold — low range (LVDV=00)	1.54	1.60	1.66	V	
V _{LW1L} V _{LW2L} V _{LW3L} V _{LW4L}	Low-voltage warning thresholds — low range <ul style="list-style-type: none"> • Level 1 falling (LVWV=00) • Level 2 falling (LVWV=01) • Level 3 falling (LVWV=10) • Level 4 falling (LVWV=11) 	1.74 1.84 1.94 2.04	1.80 1.90 2.00 2.10	1.86 1.96 2.06 2.16	V V V V	1
V _{HYSL}	Low-voltage inhibit reset/recover hysteresis — low range	—	±60	—	mV	
V _{BG}	Bandgap voltage reference	0.97	1.00	1.03	V	
t _{LPO}	Internal low power oscillator period factory trimmed	900	1000	1100	µs	

1. Rising thresholds are falling threshold + hysteresis voltage

Table 3. VBAT power operating requirements

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V _{POR_VBAT}	Falling VBAT supply POR detect voltage	0.8	1.1	1.5	V	

5.2.3 Voltage and current operating behaviors

Table 4. Voltage and current operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V _{OH}	Output high voltage — high drive strength <ul style="list-style-type: none"> • 2.7 V ≤ V_{DD} ≤ 3.6 V, I_{OH} = -9mA • 1.71 V ≤ V_{DD} ≤ 2.7 V, I_{OH} = -3mA 	V _{DD} - 0.5 V _{DD} - 0.5	— —	— —	V V	

Table continues on the next page...

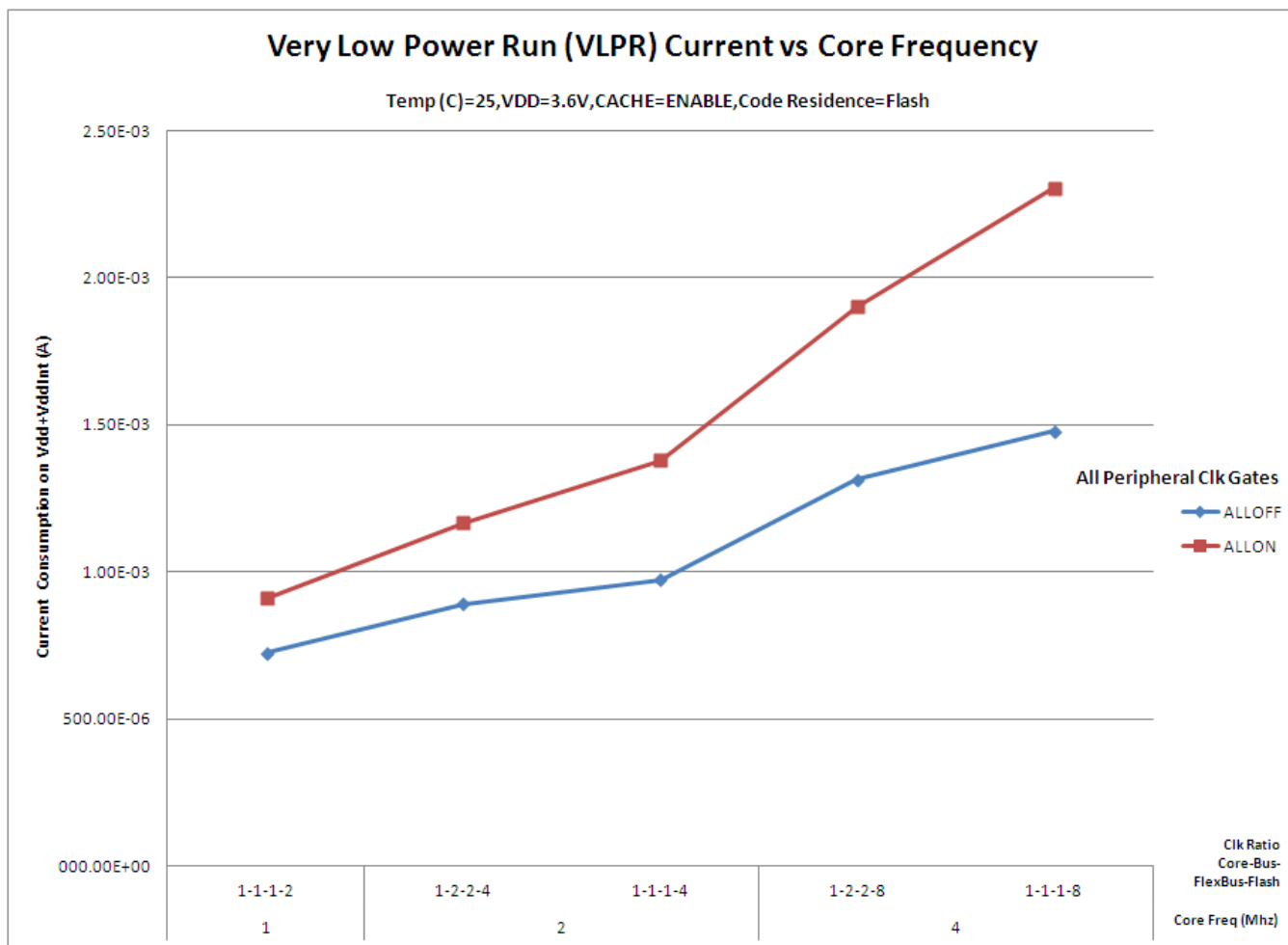


Figure 4. VLPR mode supply current vs. core frequency

5.2.6 EMC radiated emissions operating behaviors

Table 7. EMC radiated emissions operating behaviors for 256MAPBGA

Symbol	Description	Frequency band (MHz)	Typ.	Unit	Notes
V _{RE1}	Radiated emissions voltage, band 1	0.15–50	21	dBμV	1, 2, 3
V _{RE2}	Radiated emissions voltage, band 2	50–150	24	dBμV	
V _{RE3}	Radiated emissions voltage, band 3	150–500	29	dBμV	
V _{RE4}	Radiated emissions voltage, band 4	500–1000	28	dBμV	

1. Determined according to IEC Standard 61967-1, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions* and IEC Standard 61967-2, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*. Measurements were made while the microcontroller was running basic application code. The reported emission level is the value of the maximum measured emission, rounded up to the next whole number, from among the measured orientations in each frequency range.
2. V_{DD} = 3.3 V, T_A = 25 °C, f_{OSC} = 12 MHz (crystal), f_{SYS} = 72 MHz, f_{BUS} = 72 MHz
3. Determined according to IEC Standard JESD78, *IC Latch-Up Test*

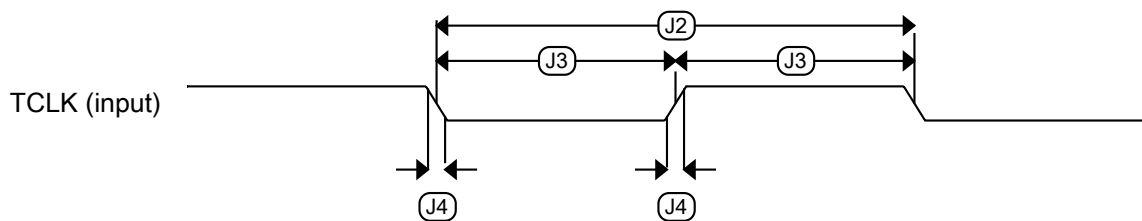


Figure 7. Test clock input timing

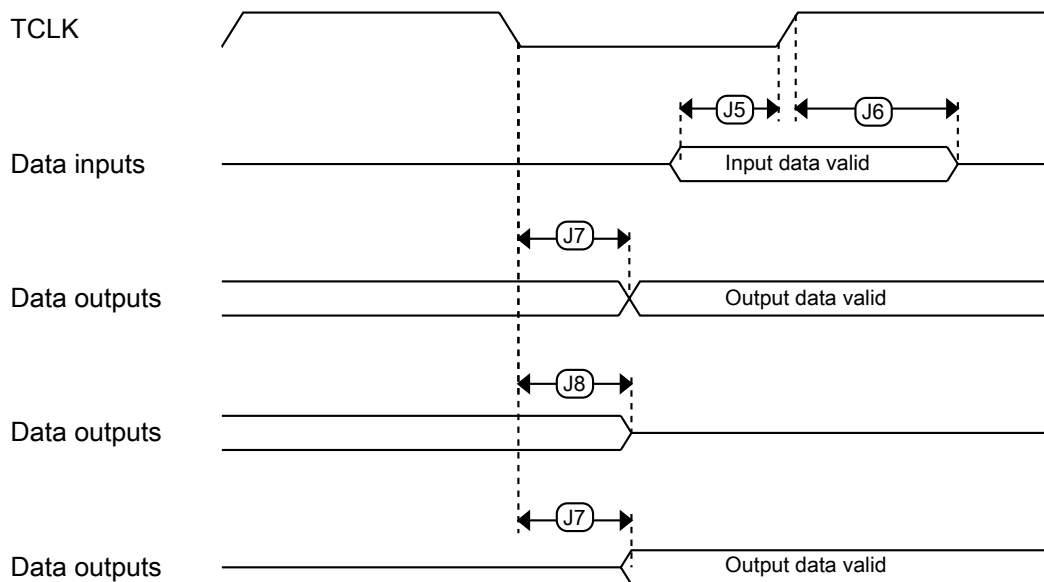


Figure 8. Boundary scan (JTAG) timing

Table 21. Flash command timing specifications (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
t_{swapx01}	<ul style="list-style-type: none"> control code 0x01 	—	200	—	μs	
t_{swapx02}	<ul style="list-style-type: none"> control code 0x02 	—	70	150	μs	
t_{swapx04}	<ul style="list-style-type: none"> control code 0x04 	—	70	150	μs	
t_{swapx08}	<ul style="list-style-type: none"> control code 0x08 	—	—	30	μs	
$t_{\text{pgmpart64k}}$	Program Partition for EEPROM execution time					
	<ul style="list-style-type: none"> 64 KB EEPROM backup 	—	235	—	ms	
$t_{\text{pgmpart256k}}$	<ul style="list-style-type: none"> 256 KB EEPROM backup 	—	240	—	ms	
	Set FlexRAM Function execution time:					
t_{setramff}	<ul style="list-style-type: none"> Control Code 0xFF 	—	205	—	μs	
$t_{\text{setram64k}}$	<ul style="list-style-type: none"> 64 KB EEPROM backup 	—	1.6	2.5	ms	
$t_{\text{setram128k}}$	<ul style="list-style-type: none"> 128 KB EEPROM backup 	—	2.7	3.8	ms	
$t_{\text{setram256k}}$	<ul style="list-style-type: none"> 256 KB EEPROM backup 	—	4.8	6.2	ms	
$t_{\text{eewr8bers}}$	Byte-write to erased FlexRAM location execution time	—	140	225	μs	3
	Byte-write to FlexRAM execution time:					
$t_{\text{eewr8b64k}}$	<ul style="list-style-type: none"> 64 KB EEPROM backup 	—	400	1700	μs	
$t_{\text{eewr8b128k}}$	<ul style="list-style-type: none"> 128 KB EEPROM backup 	—	450	1800	μs	
$t_{\text{eewr8b256k}}$	<ul style="list-style-type: none"> 256 KB EEPROM backup 	—	525	2000	μs	
$t_{\text{eewr16bers}}$	16-bit write to erased FlexRAM location execution time	—	140	225	μs	
	16-bit write to FlexRAM execution time:					
$t_{\text{eewr16b64k}}$	<ul style="list-style-type: none"> 64 KB EEPROM backup 	—	400	1700	μs	
$t_{\text{eewr16b128k}}$	<ul style="list-style-type: none"> 128 KB EEPROM backup 	—	450	1800	μs	
$t_{\text{eewr16b256k}}$	<ul style="list-style-type: none"> 256 KB EEPROM backup 	—	525	2000	μs	
$t_{\text{eewr32bers}}$	32-bit write to erased FlexRAM location execution time	—	180	275	μs	
	32-bit write to FlexRAM execution time:					
$t_{\text{eewr32b64k}}$	<ul style="list-style-type: none"> 64 KB EEPROM backup 	—	475	1850	μs	
$t_{\text{eewr32b128k}}$	<ul style="list-style-type: none"> 128 KB EEPROM backup 	—	525	2000	μs	
$t_{\text{eewr32b256k}}$	<ul style="list-style-type: none"> 256 KB EEPROM backup 	—	600	2200	μs	

1. Assumes 25MHz or greater flash clock frequency.
2. Maximum times for erase parameters based on expectations at cycling end-of-life.
3. For byte-writes to an erased FlexRAM location, the aligned word containing the byte must be erased.

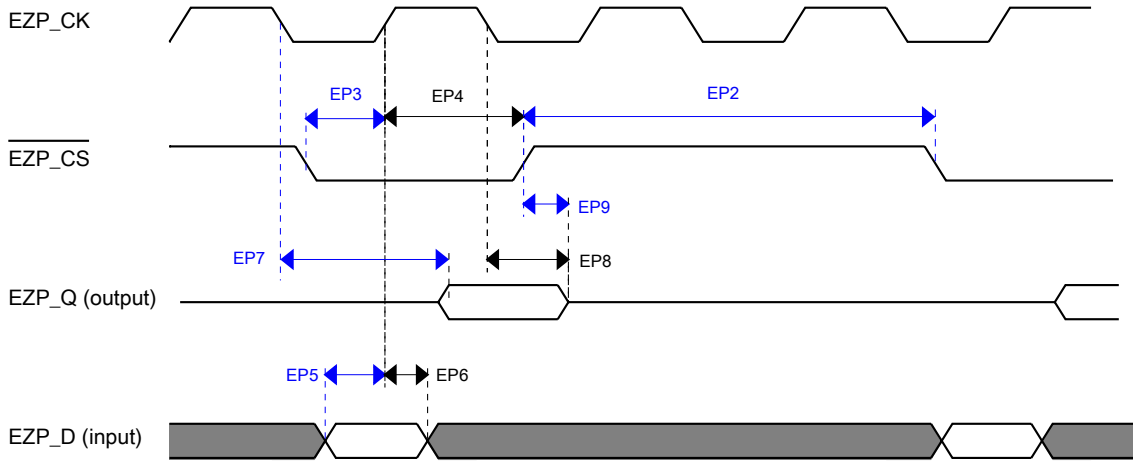


Figure 12. EzPort Timing Diagram

6.4.3 NFC specifications

The NAND flash controller (NFC) implements the interface to standard NAND flash memory devices. This section describes the timing parameters of the NFC.

In the following table:

- T_H is the flash clock high time and
- T_L is flash clock low time,

which are defined as:

$$T_{NFC} = T_L + T_H = \frac{T_{input\ clock}}{SCALER}$$

The SCALER value is derived from the fractional divider specified in the SIM's CLKDIV4 register:

$$SCALER = \frac{SIM_CLKDIV4[NFCFRAC] + 1}{SIM_CLKDIV4[NFCDIV] + 1}$$

In case the reciprocal of SCALER is an integer, the duty cycle of NFC clock is 50%, means $T_H = T_L$. In case the reciprocal of SCALER is not an integer:

$$T_L = (1 + SCALER / 2) \times \frac{T_{NFC}}{2}$$

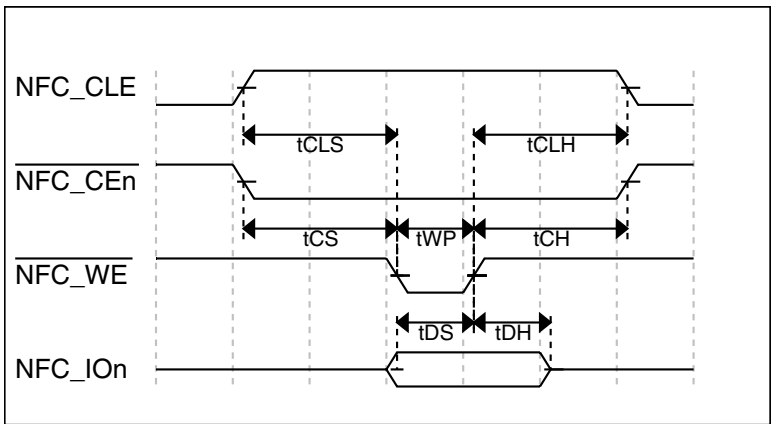


Figure 13. Command latch cycle timing

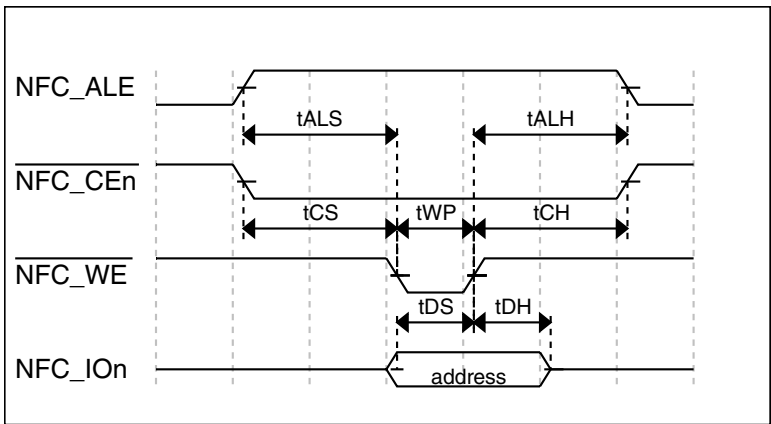


Figure 14. Address latch cycle timing

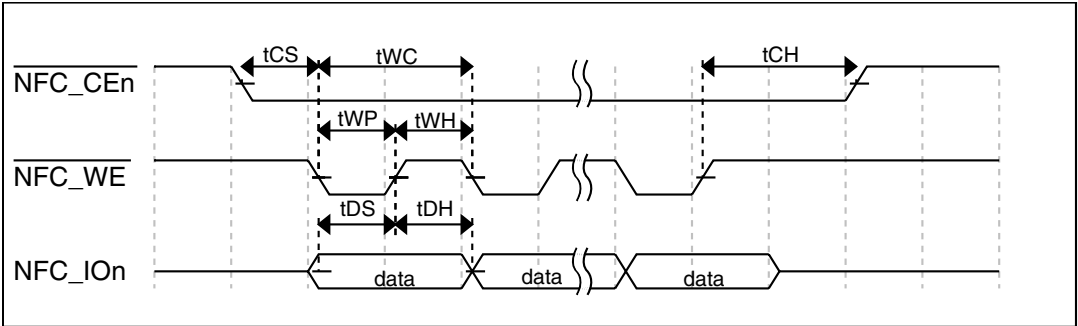
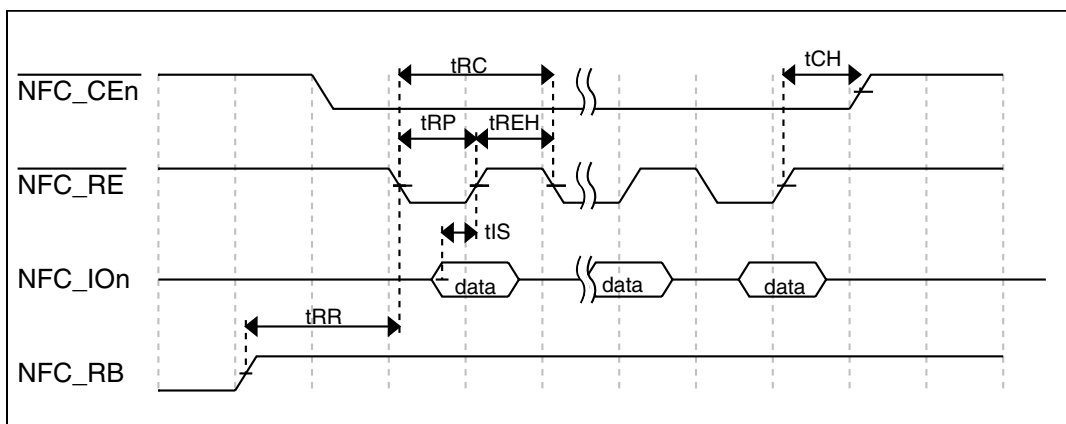
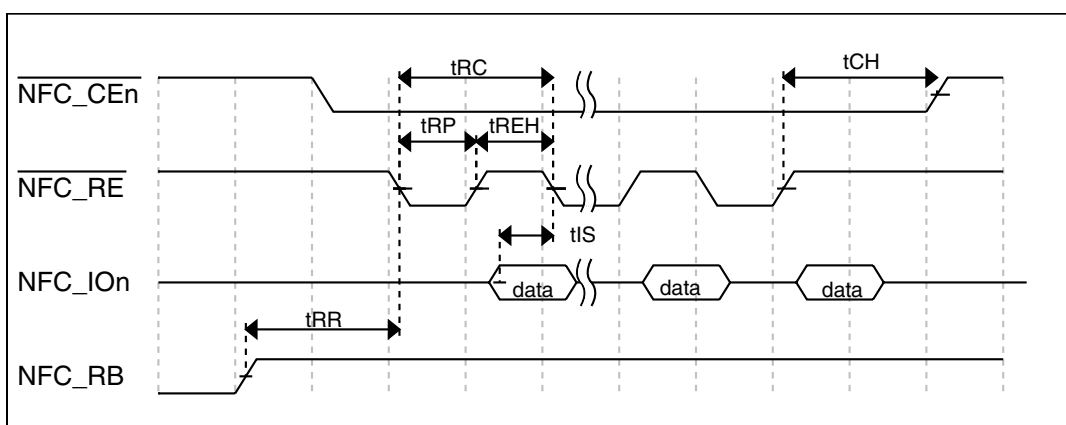


Figure 15. Write data latch cycle timing


Figure 16. Read data latch cycle timing in non-fast mode

Figure 17. Read data latch cycle timing in fast mode

6.4.4 Flexbus switching specifications

All processor bus timings are synchronous; input setup/hold and output delay are given in respect to the rising edge of a reference clock, FB_CLK. The FB_CLK frequency may be the same as the internal system bus frequency or an integer divider of that frequency.

The following timing numbers indicate when data is latched or driven onto the external bus, relative to the Flexbus output clock (FB_CLK). All other timing relationships can be derived from these values.

Table 26. Flexbus limited voltage range switching specifications

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	2.7	3.6	V	
	Frequency of operation	—	FB_CLK	MHz	
FB1	Clock period	20	—	ns	

Table continues on the next page...

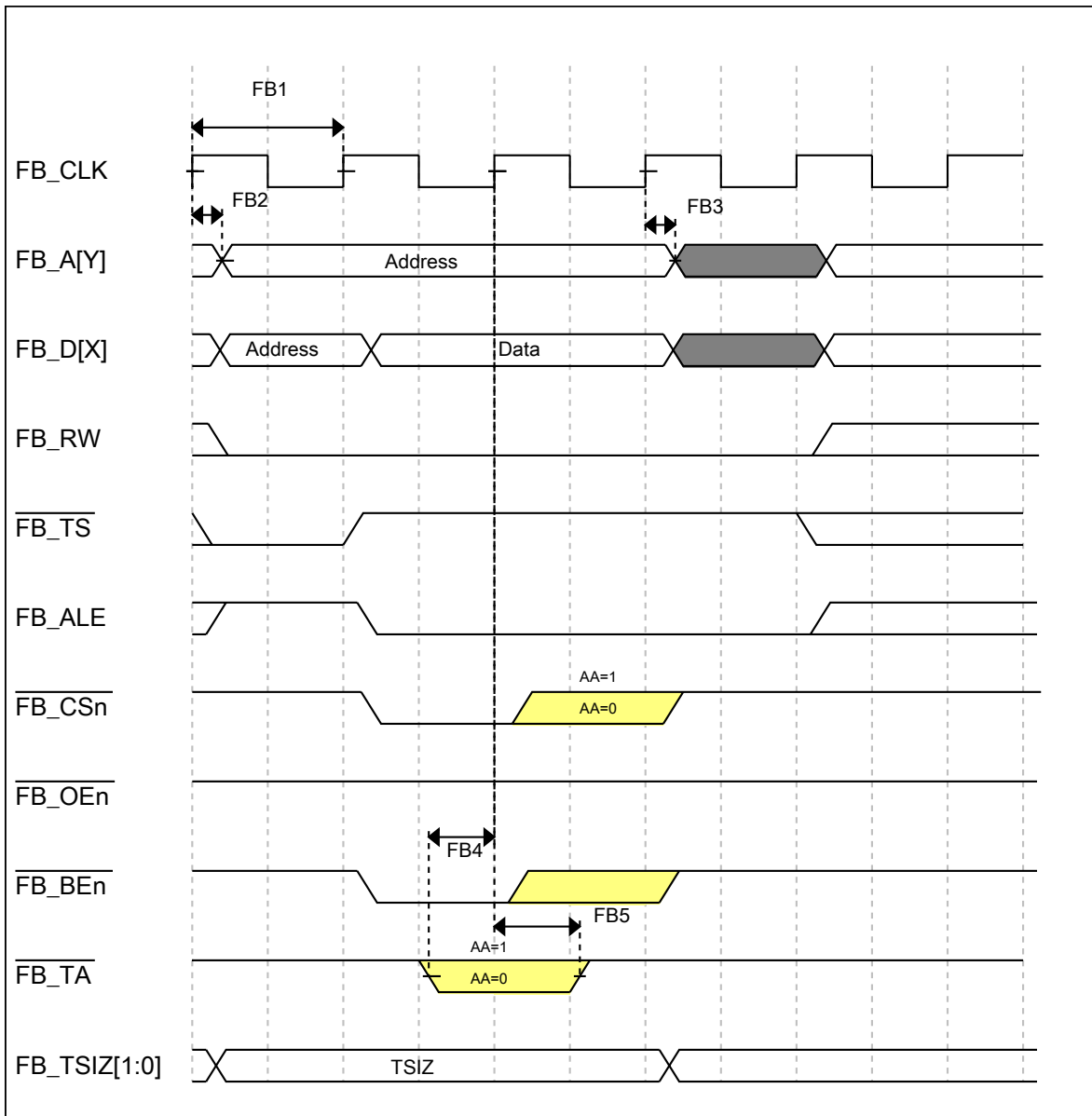


Figure 19. FlexBus write timing diagram

6.5 Security and integrity modules

There are no specifications necessary for the device's security and integrity modules.

6.6 Analog

Table 28. 16-bit ADC operating conditions

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
		Continuous conversions enabled, subsequent conversion time					

1. Typical values assume $V_{DDA} = 3.0\text{ V}$, $\text{Temp} = 25\text{ }^{\circ}\text{C}$, $f_{ADCK} = 1.0\text{ MHz}$, unless otherwise stated. Typical values are for reference only, and are not tested in production.
2. DC potential difference.
3. This resistance is external to MCU. To achieve the best results, the analog source resistance must be kept as low as possible. The results in this data sheet were derived from a system that had $< 8\text{ }\Omega$ analog source resistance. The R_{AS}/C_{AS} time constant should be kept to $< 1\text{ ns}$.
4. To use the maximum ADC conversion clock frequency, $\text{CFG2}[\text{ADHSC}]$ must be set and $\text{CFG1}[\text{ADLPC}]$ must be clear.
5. For guidelines and examples of conversion rate calculation, download the [ADC calculator tool](#).

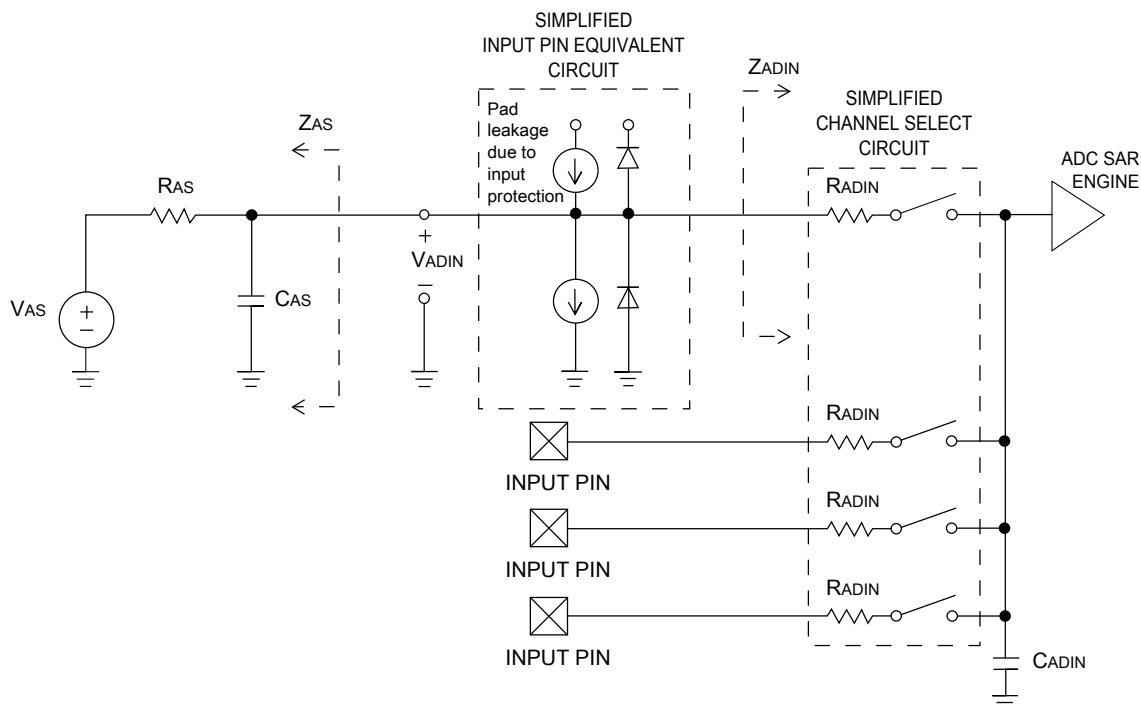


Figure 20. ADC input impedance equivalency diagram

6.6.1.2 16-bit ADC electrical characteristics

Table 29. 16-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)

Symbol	Description	Conditions ¹	Min.	Typ. ²	Max.	Unit	Notes
I_{DDA_ADC}	Supply current		0.215	—	1.7	mA	3
f_{ADACK}	ADC asynchronous clock source	<ul style="list-style-type: none"> • $\text{ADLPC} = 1, \text{ADHSC} = 0$ • $\text{ADLPC} = 1, \text{ADHSC} = 1$ 	1.2	2.4	3.9	MHz	$t_{ADACK} = 1/f_{ADACK}$
			2.4	4.0	6.1	MHz	

Table continues on the next page...

Table 30. 16-bit ADC with PGA operating conditions

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
		No ADC hardware averaging Continuous conversions enabled Peripheral clock = 50 MHz					

1. Typical values assume $V_{DDA} = 3.0\text{ V}$, $\text{Temp} = 25^\circ\text{C}$, $f_{\text{ADCK}} = 6\text{ MHz}$ unless otherwise stated. Typical values are for reference only and are not tested in production.
2. ADC must be configured to use the internal voltage reference (VREF_OUT)
3. PGA reference is internally connected to the VREF_OUT pin. If the user wishes to drive VREF_OUT with a voltage other than the output of the VREF module, the VREF module must be disabled.
4. For single ended configurations the input impedance of the driven input is $R_{\text{PGAD}}/2$
5. The analog source resistance (R_{AS}), external to MCU, should be kept as minimum as possible. Increased R_{AS} causes drop in PGA gain without affecting other performances. This is not dependent on ADC clock frequency.
6. The minimum sampling time is dependent on input signal frequency and ADC mode of operation. A minimum of $1.25\mu\text{s}$ time should be allowed for $F_{\text{in}}=4\text{ kHz}$ at 16-bit differential mode. Recommended ADC setting is: ADLSMP=1, ADLSTS=2 at 8 MHz ADC clock.
7. ADC clock = 18 MHz, ADLSMP = 1, ADLST = 00, ADHSC = 1
8. ADC clock = 12 MHz, ADLSMP = 1, ADLST = 01, ADHSC = 1

6.6.1.4 16-bit ADC with PGA characteristics

Table 31. 16-bit ADC with PGA characteristics

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
$I_{\text{DDA_PGA}}$	Supply current	Low power (ADC_PGA[PGALPb]=0)	—	420	644	μA	2
$I_{\text{DC_PGA}}$	Input DC current		$\frac{2}{R_{\text{PGAD}}} \left(\frac{V_{\text{REFPGA}} \times 0.583 - V_{\text{CM}}}{\text{Gain} + 1} \right)$			A	3
		Gain =1, $V_{\text{REFPGA}}=1.2\text{V}$, $V_{\text{CM}}=0.5\text{V}$	—	1.54	—	μA	
		Gain =64, $V_{\text{REFPGA}}=1.2\text{V}$, $V_{\text{CM}}=0.1\text{V}$	—	0.57	—	μA	
G	Gain ⁴	<ul style="list-style-type: none"> • PGAG=0 • PGAG=1 • PGAG=2 • PGAG=3 • PGAG=4 • PGAG=5 • PGAG=6 	0.95	1	1.05		$R_{\text{AS}} < 100\Omega$
BW	Input signal bandwidth	• 16-bit modes	—	—	4	kHz	
		• < 16-bit modes	—	—	40	kHz	
PSRR	Power supply rejection ratio	Gain=1	—	-84	—	dB	$V_{\text{DDA}} = 3\text{V} \pm 100\text{mV}$,

Table continues on the next page...

Table 31. 16-bit ADC with PGA characteristics (continued)

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
		<ul style="list-style-type: none"> Gain=1, Average=32 Gain=2, Average=32 Gain=4, Average=32 Gain=8, Average=32 Gain=16, Average=32 Gain=32, Average=32 Gain=64, Average=32 	11.0	14.3	—	bits	
			7.9	13.8	—	bits	
			7.3	13.1	—	bits	
			6.8	12.5	—	bits	
			6.8	11.5	—	bits	
			7.5	10.6	—	bits	
SINAD	Signal-to-noise plus distortion ratio	See ENOB	6.02 × ENOB + 1.76			dB	

1. Typical values assume $V_{DDA} = 3.0V$, $Temp = 25^{\circ}C$, $f_{ADCK} = 6MHz$ unless otherwise stated.
2. This current is a PGA module adder, in addition to ADC conversion currents.
3. Between IN+ and IN-. The PGA draws a DC current from the input terminals. The magnitude of the DC current is a strong function of input common mode voltage (V_{CM}) and the PGA gain.
4. $Gain = 2^{PGAG}$
5. After changing the PGA gain setting, a minimum of 2 ADC+PGA conversions should be ignored.
6. Limit the input signal swing so that the PGA does not saturate during operation. Input signal swing is dependent on the PGA reference voltage and gain setting.

6.6.2 CMP and 6-bit DAC electrical specifications

Table 32. Comparator and 6-bit DAC electrical specifications

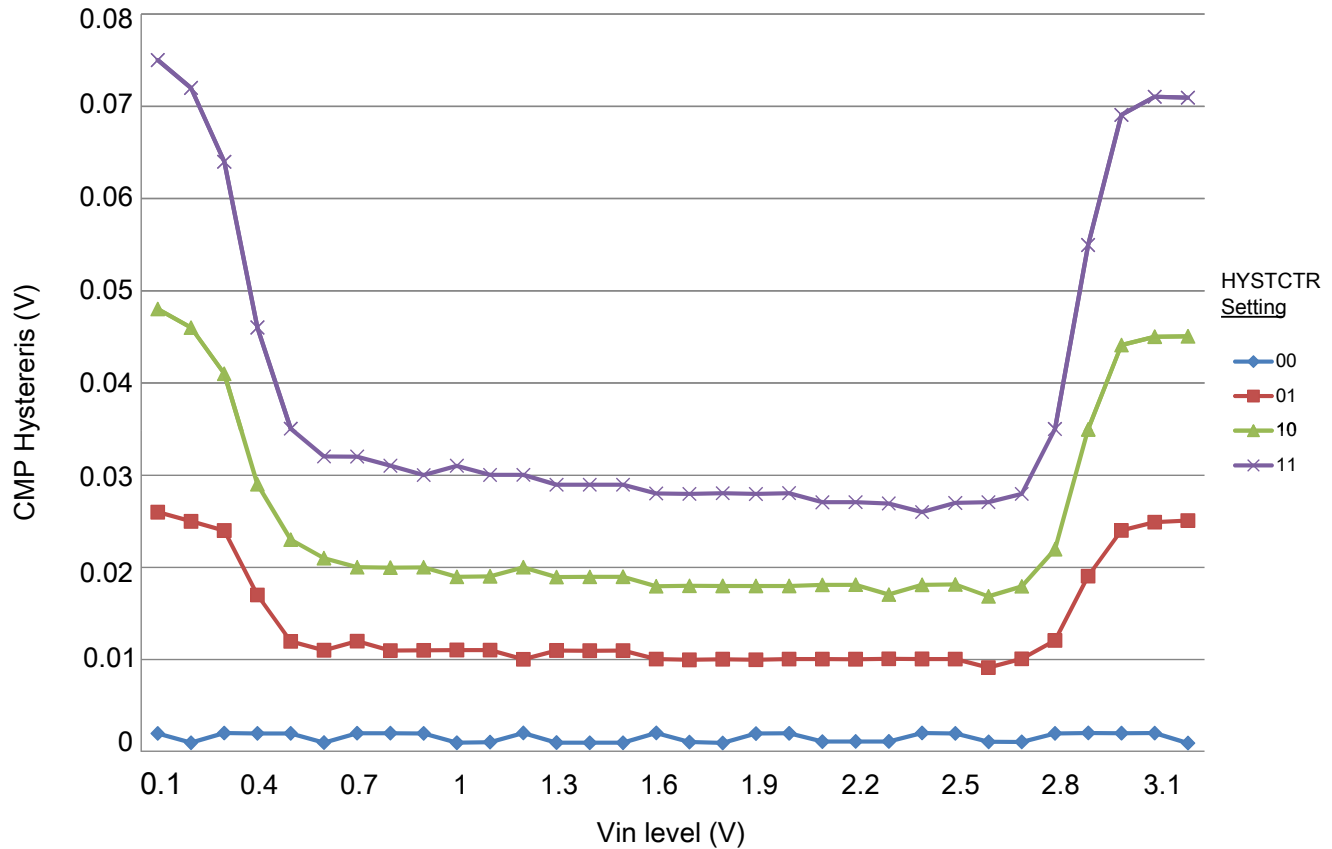
Symbol	Description	Min.	Typ.	Max.	Unit
V_{DD}	Supply voltage	1.71	—	3.6	V
I_{DDHS}	Supply current, High-speed mode (EN=1, PMODE=1)	—	—	200	μA
$I_{DDL S}$	Supply current, low-speed mode (EN=1, PMODE=0)	—	—	20	μA
V_{AIN}	Analog input voltage	$V_{SS} - 0.3$	—	V_{DD}	V
V_{AIO}	Analog input offset voltage	—	—	20	mV
V_H	Analog comparator hysteresis ¹ <ul style="list-style-type: none"> CR0[HYSTCTR] = 00 CR0[HYSTCTR] = 01 CR0[HYSTCTR] = 10 CR0[HYSTCTR] = 11 	—	5	—	mV
		—	10	—	mV
		—	20	—	mV
		—	30	—	mV
V_{CMPOH}	Output high	$V_{DD} - 0.5$	—	—	V
V_{CMPOI}	Output low	—	—	0.5	V
t_{DHS}	Propagation delay, high-speed mode (EN=1, PMODE=1)	20	50	200	ns
t_{DLS}	Propagation delay, low-speed mode (EN=1, PMODE=0)	80	250	600	ns
	Analog comparator initialization delay ²	—	—	40	μs
I_{DAC6b}	6-bit DAC current adder (enabled)	—	7	—	μA

Table continues on the next page...

Table 32. Comparator and 6-bit DAC electrical specifications (continued)

Symbol	Description	Min.	Typ.	Max.	Unit
INL	6-bit DAC integral non-linearity	-0.5	—	0.5	LSB ³
DNL	6-bit DAC differential non-linearity	-0.3	—	0.3	LSB

1. Typical hysteresis is measured with input voltage range limited to 0.6 to $V_{DD}-0.6$ V.
2. Comparator initialization delay is defined as the time between software writes to change control inputs (Writes to CMP_DACCR[DACEN], CMP_DACCR[VRSEL], CMP_DACCR[VOSEL], CMP_MUXCR[PSEL], and CMP_MUXCR[MSEL]) and the comparator output settling to a stable level.
3. $1 \text{ LSB} = V_{\text{reference}}/64$


Figure 23. Typical hysteresis vs. Vin level (VDD = 3.3 V, PMODE = 0)

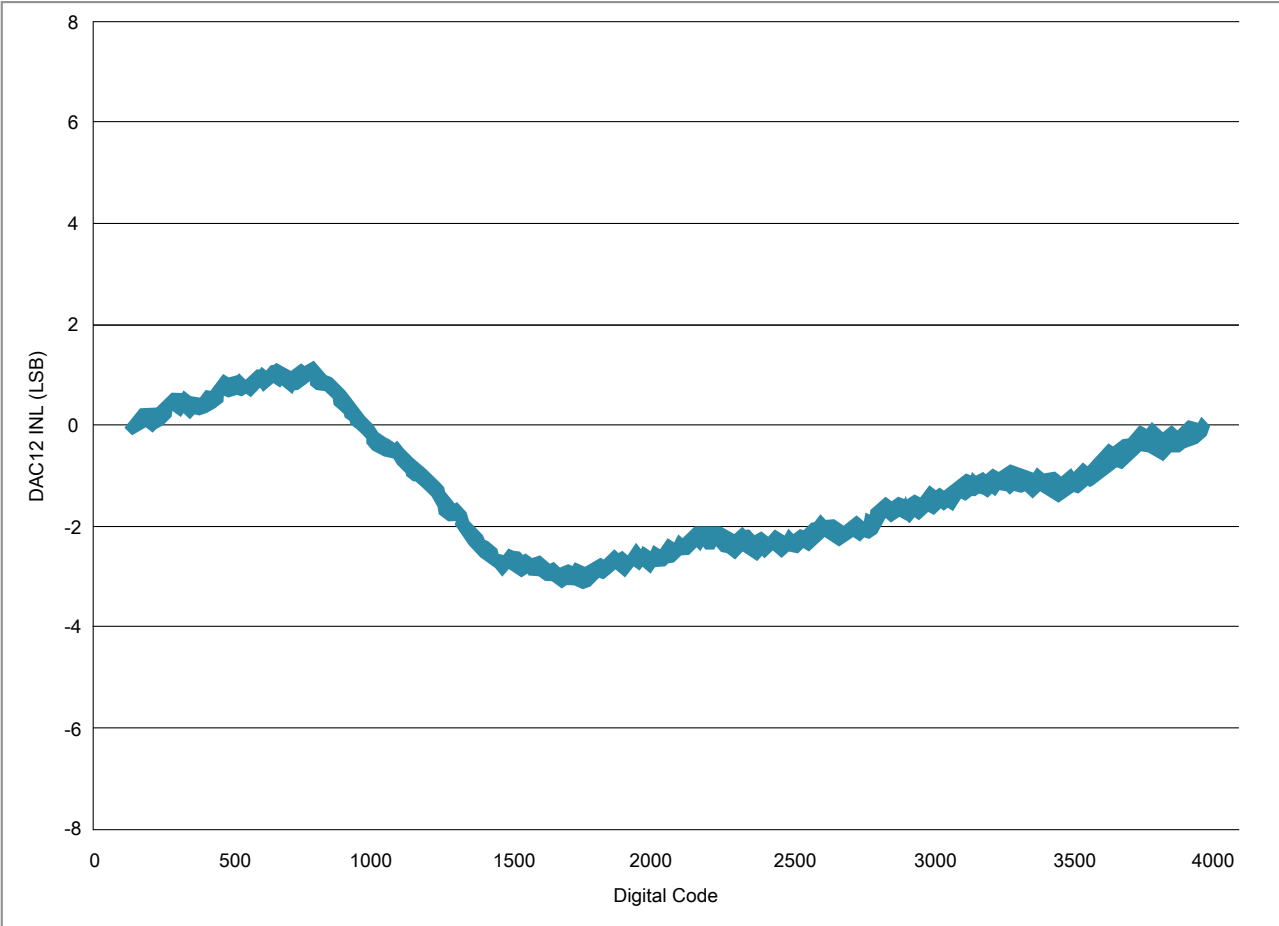


Figure 25. Typical INL error vs. digital code

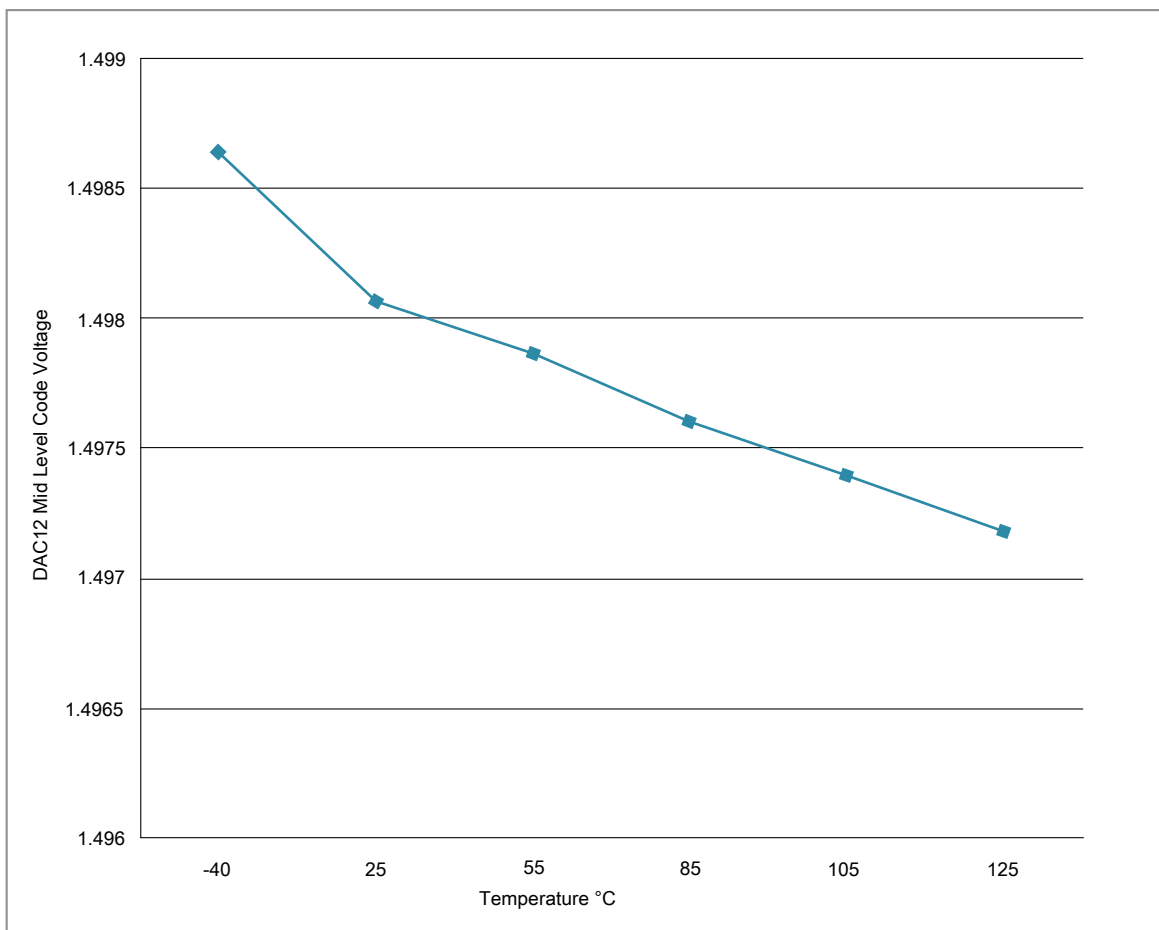


Figure 26. Offset at half scale vs. temperature

6.6.4 Voltage reference electrical specifications

Table 35. VREF full-range operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
V_{DDA}	Supply voltage	1.71	3.6	V	
T_A	Temperature	Operating temperature range of the device		°C	
C_L	Output load capacitance	100		nF	1, 2

1. C_L must be connected to VREF_OUT if the VREF_OUT functionality is being used for either an internal or external reference.
2. The load capacitance should not exceed +/-25% of the nominal specified C_L value over the operating temperature range of the device.

6.8.5 ULPI timing specifications

The ULPI interface is fully compliant with the industry standard UTMI+ Low Pin Interface. Control and data timing requirements for the ULPI pins are given in the following table. These timings apply to synchronous mode only. All timings are measured with respect to the clock as seen at the USB_CLKIN pin.

Table 43. ULPI timing specifications

Num	Description	Min.	Typ.	Max.	Unit
	USB_CLKIN operating frequency	—	60	—	MHz
	USB_CLKIN duty cycle	—	50	—	%
U1	USB_CLKIN clock period	—	16.67	—	ns
U2	Input setup (control and data)	5	—	—	ns
U3	Input hold (control and data)	1	—	—	ns
U4	Output valid (control and data)	—	—	9.5	ns
U5	Output hold (control and data)	1	— </td <td>—</td> <td>ns</td>	—	ns

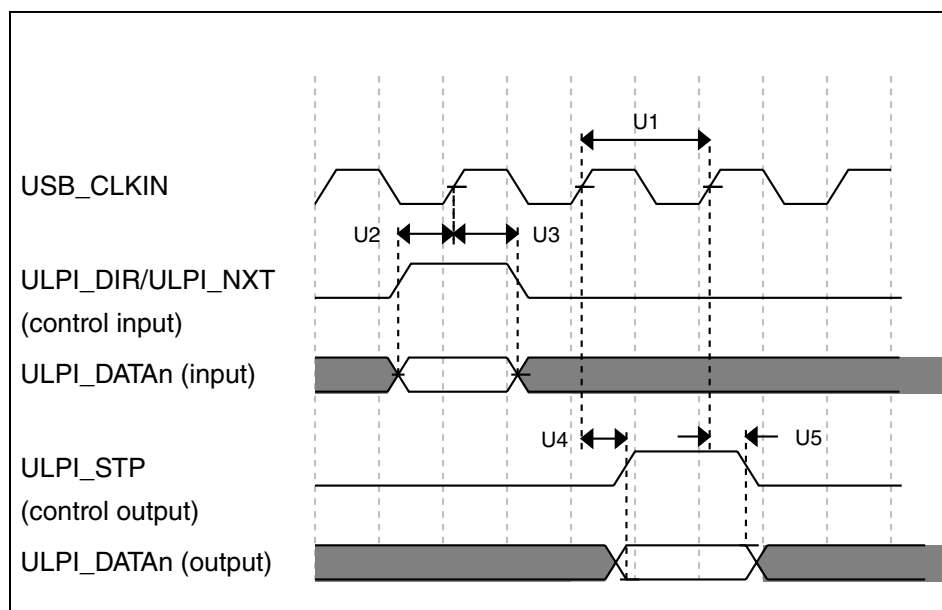


Figure 29. ULPI timing diagram

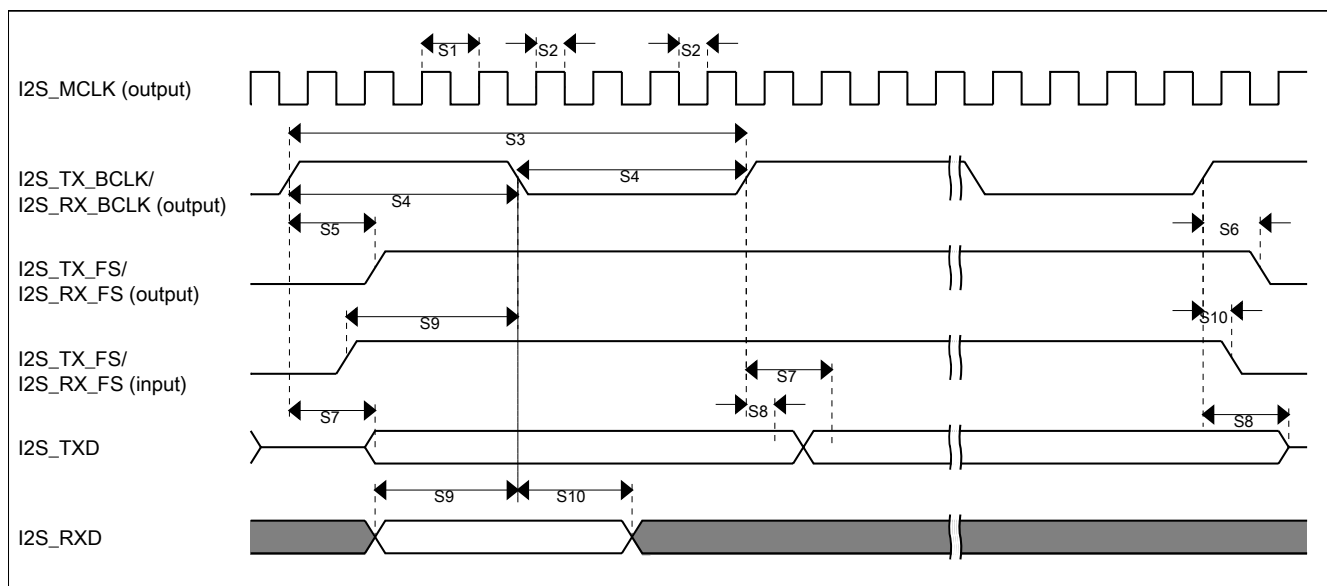


Figure 38. I2S/SAI timing — master modes

Table 54. I2S/SAI slave mode timing in Normal Run, Wait and Stop modes (full voltage range)

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	80	—	ns
S12	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input)	45%	55%	MCLK period
S13	I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK	5.8	—	ns
S14	I2S_TX_FS/I2S_RX_FS input hold after I2S_TX_BCLK/I2S_RX_BCLK	2	—	ns
S15	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid <ul style="list-style-type: none"> • Multiple SAI Synchronous mode • All other modes 	—	24 20.6	ns
S16	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid	0	—	ns
S17	I2S_RXD setup before I2S_RX_BCLK	5.8	—	ns
S18	I2S_RXD hold after I2S_RX_BCLK	2	—	ns
S19	I2S_TX_FS input assertion to I2S_TXD output valid ¹	—	25	ns

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

Table 58. Pins with active pull control after reset

Pin	Active pull direction after reset
PTA0	pulldown
PTA1	pullup
PTA3	pullup
PTA4	pullup
RESET_b	pullup

8.2 K60 Signal Multiplexing and Pin Assignments

The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

144 LQFP	144 MAP BGA	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
—	L5	RTC_WAKEUP_B	RTC_WAKEUP_B	RTC_WAKEUP_B								
—	M5	NC	NC	NC								
—	A10	NC	NC	NC								
—	B10	NC	NC	NC								
—	C10	NC	NC	NC								
1	D3	PTE0	ADC1_SE4a	ADC1_SE4a	PTE0	SPI1_PCS1	UART1_TX	SDHC0_D1		I2C1_SDA	RTC_CLKOUT	
2	D2	PTE1/LLWU_P0	ADC1_SE5a	ADC1_SE5a	PTE1/LLWU_P0	SPI1_SOUT	UART1_RX	SDHC0_D0		I2C1_SCL	SPI1_SIN	
3	D1	PTE2/LLWU_P1	ADC1_SE6a	ADC1_SE6a	PTE2/LLWU_P1	SPI1_SCK	UART1_CTS_b	SDHC0_DCLK				
4	E4	PTE3	ADC1_SE7a	ADC1_SE7a	PTE3	SPI1_SIN	UART1_RTS_b	SDHC0_CMD			SPI1_SOUT	
5	E5	VDD	VDD	VDD								
6	F6	VSS	VSS	VSS								
7	E3	PTE4/LLWU_P2	DISABLED		PTE4/LLWU_P2	SPI1_PCS0	UART3_TX	SDHC0_D3				
8	E2	PTE5	DISABLED		PTE5	SPI1_PCS2	UART3_RX	SDHC0_D2		FTM3_CH0		
9	E1	PTE6	DISABLED		PTE6	SPI1_PCS3	UART3_CTS_b	I2S0_MCLK		FTM3_CH1	USB_SOF_OUT	
10	F4	PTE7	DISABLED		PTE7		UART3_RTS_b	I2S0_RXD0		FTM3_CH2		
11	F3	PTE8	ADC2_SE16	ADC2_SE16	PTE8	I2S0_RXD1	UART5_TX	I2S0_RX_FS		FTM3_CH3		
12	F2	PTE9	ADC2_SE17	ADC2_SE17	PTE9	I2S0_TXD1	UART5_RX	I2S0_RX_BCLK		FTM3_CH4		